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### **Understanding Embedded - FPGAs (Field Programmable Gate Array)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### **Details**

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	276480
Number of I/O	444
Number of Gates	1500000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	676-BGA
Supplier Device Package	676-FBGA (27x27)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/a3pe1500-2fg676i">https://www.e-xfl.com/product-detail/microchip-technology/a3pe1500-2fg676i</a>

## Temperature Grade Offerings

Package	A3PE600	A3PE1500	A3PE3000
<b>Cortex-M1 Devices</b>		<b>M1A3PE1500</b>	<b>M1A3PE3000</b>
PQ208	C, I	C, I	C, I
FG256	C, I	–	–
FG324	–	–	C, I
FG484	C, I	C, I	C, I
FG676	–	C, I	–
FG896	–	–	C, I

*Note:* C = Commercial temperature range: 0°C to 70°C ambient temperature  
 I = Industrial temperature range: –40°C to 85°C ambient temperature

## Speed Grade and Temperature Grade Matrix

Temperature Grade	Std.	–1	–2
C <sup>1</sup>	✓	✓	✓
I <sup>2</sup>	✓	✓	✓

*Notes:*

1. C = Commercial temperature range: 0°C to 70°C ambient temperature
2. I = Industrial temperature range: –40°C to 85°C ambient temperature

References made to ProASIC3E devices also apply to ARM-enabled ProASIC3E devices. The ARM-enabled part numbers start with M1 (Cortex-M1).

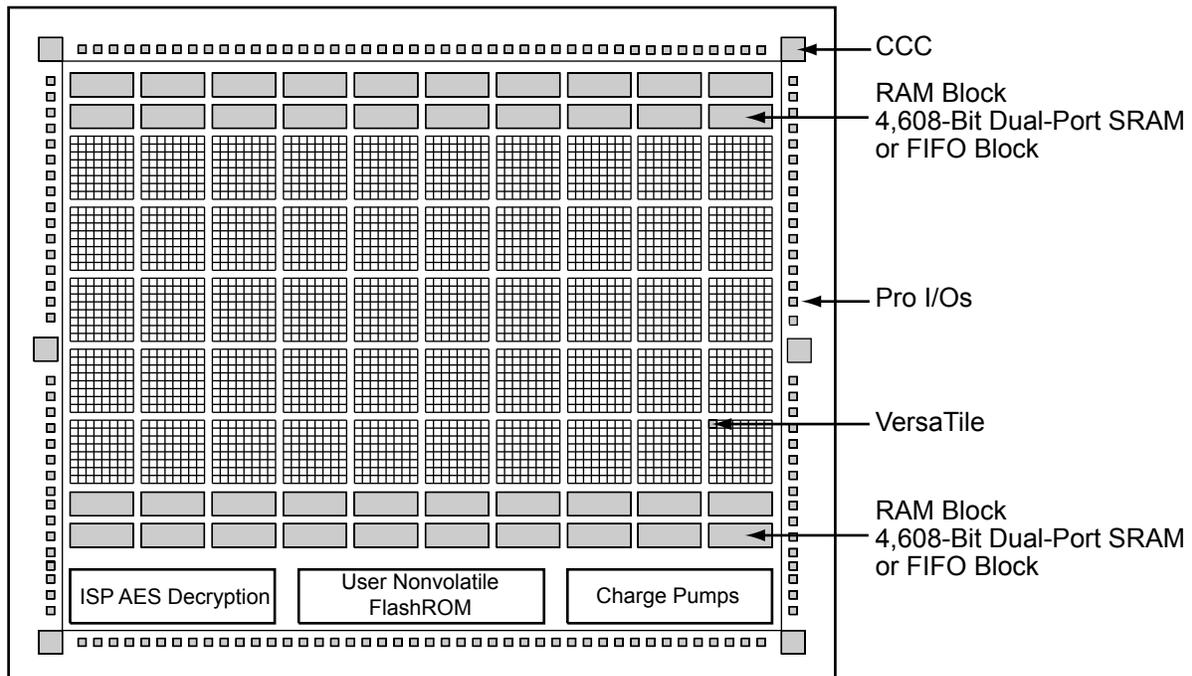
Contact your local Microsemi SoC Products Group representative for device availability:  
[www.microsemi.com/index.php?option=com\\_content&id=135&lang=en&view=article](http://www.microsemi.com/index.php?option=com_content&id=135&lang=en&view=article).

## Advanced Architecture

The proprietary ProASIC3E architecture provides granularity comparable to standard-cell ASICs. The ProASIC3E device consists of five distinct and programmable architectural features (Figure 1-1 on page 3):

- FPGA VersaTiles
- Dedicated FlashROM
- Dedicated SRAM/FIFO memory
- Extensive CCCs and PLLs
- Pro I/O structure

The FPGA core consists of a sea of VersaTiles. Each VersaTile can be configured as a three-input logic function, a D-flip-flop (with or without enable), or a latch by programming the appropriate flash switch interconnections. The versatility of the ProASIC3E core tile as either a three-input lookup table (LUT) equivalent or as a D-flip-flop/latch with enable allows for efficient use of the FPGA fabric. The VersaTile capability is unique to the ProASIC family of third-generation architecture Flash FPGAs. VersaTiles are connected with any of the four levels of routing hierarchy. Flash switches are distributed throughout the device to provide nonvolatile, reconfigurable interconnect programming. Maximum core utilization is possible for virtually any design.



**Figure 1-1 • ProASIC3E Device Architecture Overview**

### Timing Characteristics

**Table 2-27 • 3.3 V LVTTTL / 3.3 V LVCMOS High Slew**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 3.0\text{ V}$

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{PYS}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
2 mA	Std.	0.66	7.88	0.04	1.20	1.57	0.43	8.03	6.70	2.69	2.59	10.26	8.94	ns
	-1	0.56	6.71	0.04	1.02	1.33	0.36	6.83	5.70	2.29	2.20	8.73	7.60	ns
	-2	0.49	5.89	0.03	0.90	1.17	0.32	6.00	5.01	2.01	1.93	7.67	6.67	ns
4 mA	Std.	0.66	7.88	0.04	1.20	1.57	0.43	8.03	6.70	2.69	2.59	10.26	8.94	ns
	-1	0.56	6.71	0.04	1.02	1.33	0.36	6.83	5.70	2.29	2.20	8.73	7.60	ns
	-2	0.49	5.89	0.03	0.90	1.17	0.32	6.00	5.01	2.01	1.93	7.67	6.67	ns
6 mA	Std.	0.66	5.08	0.04	1.20	1.57	0.43	5.17	4.14	3.05	3.21	7.41	6.38	ns
	-1	0.56	4.32	0.04	1.02	1.33	0.36	4.40	3.52	2.59	2.73	6.30	5.43	ns
	-2	0.49	3.79	0.03	0.90	1.17	0.32	3.86	3.09	2.28	2.40	5.53	4.76	ns
8 mA	Std.	0.66	5.08	0.04	1.20	1.57	0.43	5.17	4.14	3.05	3.21	7.41	6.38	ns
	-1	0.56	4.32	0.04	1.02	1.33	0.36	4.40	3.52	2.59	2.73	6.30	5.43	ns
	-2	0.49	3.79	0.03	0.90	1.17	0.32	3.86	3.09	2.28	2.40	5.53	4.76	ns
12 mA	Std.	0.66	3.67	0.04	1.20	1.57	0.43	3.74	2.87	3.28	3.61	5.97	5.11	ns
	-1	0.56	3.12	0.04	1.02	1.33	0.36	3.18	2.44	2.79	3.07	5.08	4.34	ns
	-2	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81	ns
16 mA	Std.	0.66	3.46	0.04	1.20	1.57	0.43	3.53	2.61	3.33	3.72	5.76	4.84	ns
	-1	0.56	2.95	0.04	1.02	1.33	0.36	3.00	2.22	2.83	3.17	4.90	4.12	ns
	-2	0.49	2.59	0.03	0.90	1.17	0.32	2.63	1.95	2.49	2.78	4.30	3.62	ns
24 mA	Std.	0.66	3.21	0.04	1.20	1.57	0.43	3.27	2.16	3.39	4.13	5.50	4.39	ns
	-1	0.56	2.73	0.04	1.02	1.33	0.36	2.78	1.83	2.88	3.51	4.68	3.74	ns
	-2	0.49	2.39	0.03	0.90	1.17	0.32	2.44	1.61	2.53	3.08	4.11	3.28	ns

**Notes:**

1. Software default selection highlighted in gray.
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.

**Table 2-28 • 3.3 V LVTTTL / 3.3 V LVCMOS Low Slew**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 3.0\text{ V}$

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{PYS}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
2 mA	Std.	0.66	11.01	0.04	1.20	1.57	0.43	11.21	9.05	2.69	2.44	13.45	11.29	ns
	-1	0.56	9.36	0.04	1.02	1.33	0.36	9.54	7.70	2.29	2.08	11.44	9.60	ns
	-2	0.49	8.22	0.03	0.90	1.17	0.32	8.37	6.76	2.01	1.82	10.04	8.43	ns
4 mA	Std.	0.66	11.01	0.04	1.20	1.57	0.43	11.21	9.05	2.69	2.44	13.45	11.29	ns
	-1	0.56	9.36	0.04	1.02	1.33	0.36	9.54	7.70	2.29	2.08	11.44	9.60	ns
	-2	0.49	8.22	0.03	0.90	1.17	0.32	8.37	6.76	2.01	1.82	10.04	8.43	ns
6 mA	Std.	0.66	7.86	0.04	1.20	1.57	0.43	8.01	6.44	3.04	3.06	10.24	8.68	ns
	-1	0.56	6.69	0.04	1.02	1.33	0.36	6.81	5.48	2.58	2.61	8.71	7.38	ns
	-2	0.49	5.87	0.03	0.90	1.17	0.32	5.98	4.81	2.27	2.29	7.65	6.48	ns
8 mA	Std.	0.66	7.86	0.04	1.20	1.57	0.43	8.01	6.44	3.04	3.06	10.24	8.68	ns
	-1	0.56	6.69	0.04	1.02	1.33	0.36	6.81	5.48	2.58	2.61	8.71	7.38	ns
	-2	0.49	5.87	0.03	0.90	1.17	0.32	5.98	4.81	2.27	2.29	7.65	6.48	ns

### 1.8 V LVCMOS

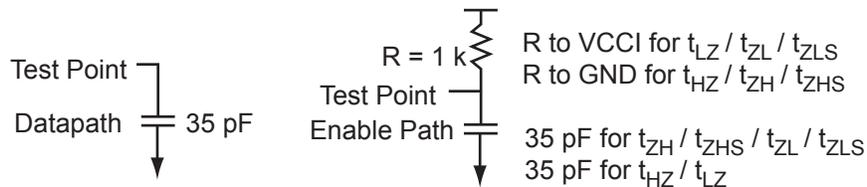
Low-Voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.8 V applications. It uses a 1.8 V input buffer and a push-pull output buffer.

**Table 2-37 • Minimum and Maximum DC Input and Output Levels**

1.8 V LVCMOS	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μA <sup>4</sup>	μA <sup>4</sup>
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	2	2	11	9	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	4	4	22	17	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	6	6	44	35	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	8	8	51	45	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	12	12	74	91	10	10
16 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	16	16	74	91	10	10

**Notes:**

1. IIL is the input leakage current per I/O pin over recommended operation conditions where  $-0.3\text{ V} < V_{IN} < V_{IL}$ .
2. IIH is the input leakage current per I/O pin over recommended operating conditions  $V_{IH} < V_{IN} < V_{CCI}$ . Input current is larger when operating outside recommended ranges.
3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
4. Currents are measured at 85°C junction temperature.
5. Software default selection highlighted in gray.



**Figure 2-9 • AC Loading**

**Table 2-38 • AC Waveforms, Measuring Points, and Capacitive Loads**

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	1.8	0.9	-	35

*Note:* \*Measuring point = Vtrip. See Table 2-15 on page 2-18 for a complete table of trip points.

## 2.5 V GTL

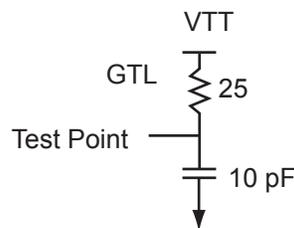
Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 2.5 V.

**Table 2-51 • Minimum and Maximum DC Input and Output Levels**

2.5 GTL Drive Strength	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL	IIH
	Min., V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>1</sup>	Max. mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
20 mA <sup>3</sup>	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	-	20	20	124	169	10	10

**Notes:**

1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
2. Currents are measured at 85°C junction temperature.
3. Output drive strength is below JEDEC specification.



**Figure 2-13 • AC Loading**

**Table 2-52 • AC Waveforms, Measuring Points, and Capacitive Loads**

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.05	VREF + 0.05	0.8	0.8	1.2	10

*Note:* \*Measuring point = Vtrip. See Table 2-15 on page 2-18 for a complete table of trip points.

### Timing Characteristics

**Table 2-53 • 2.5 V GTL**

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,  
Worst-Case VCCI = 3.0 V VREF = 0.8 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.60	2.13	0.04	2.46	0.43	2.16	2.13			4.40	4.36	ns
-1	0.51	1.81	0.04	2.09	0.36	1.84	1.81			3.74	3.71	ns
-2	0.45	1.59	0.03	1.83	0.32	1.61	1.59			3.28	3.26	ns

*Note:* For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

### SSTL2 Class I

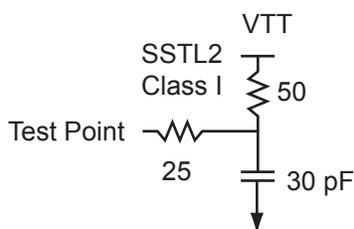
Stub-Speed Terminated Logic for 2.5 V memory bus standard (JESD8-9). ProASIC3E devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

**Table 2-66 • Minimum and Maximum DC Input and Output Levels**

SSTL2 Class I	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL	IIH
	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>1</sup>	Max. mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
15 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.54	VCCI - 0.62	15	15	87	83	10	10

Notes:

1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
2. Currents are measured at 85°C junction temperature.



**Figure 2-18 • AC Loading**

**Table 2-67 • AC Waveforms, Measuring Points, and Capacitive Loads**

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.25	1.25	1.25	30

Note: \*Measuring point = V<sub>trip</sub>. See Table 2-15 on page 2-18 for a complete table of trip points.

### Timing Characteristics

**Table 2-68 • SSTL 2 Class I**

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V, VREF = 1.25 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.13	0.04	1.33	0.43	2.17	1.85			4.40	4.08	ns
-1	0.56	1.81	0.04	1.14	0.36	1.84	1.57			3.74	3.47	ns
-2	0.49	1.59	0.03	1.00	0.32	1.62	1.38			3.29	3.05	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

## Output Register

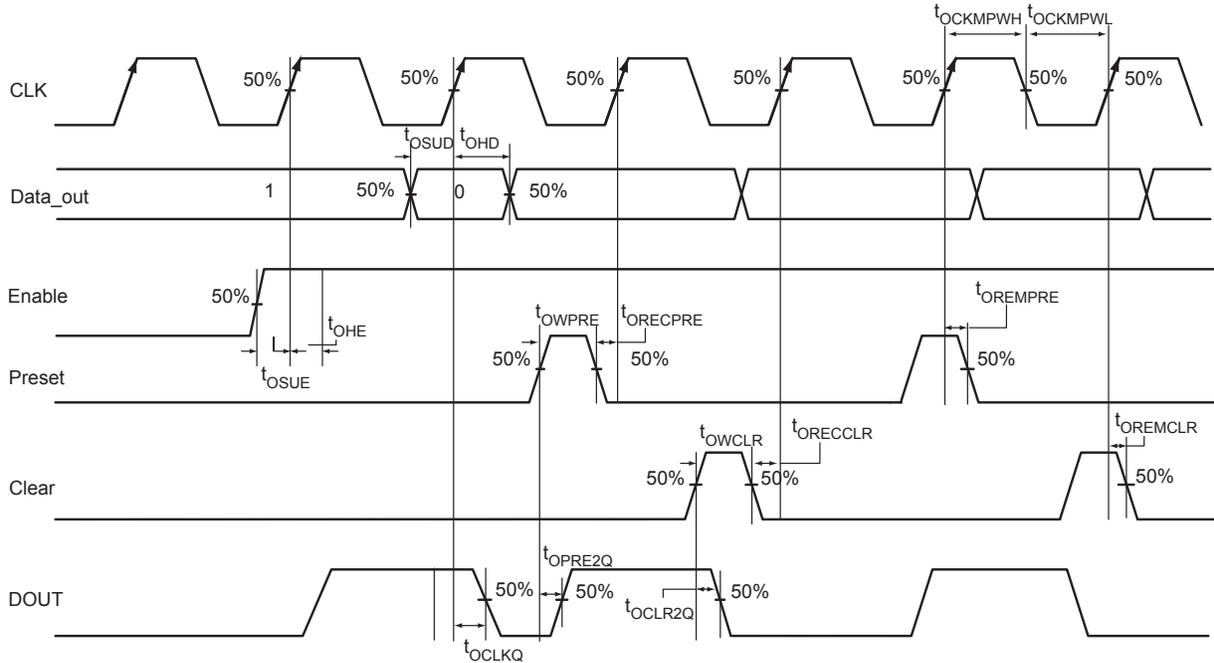


Figure 2-28 • Output Register Timing Diagram

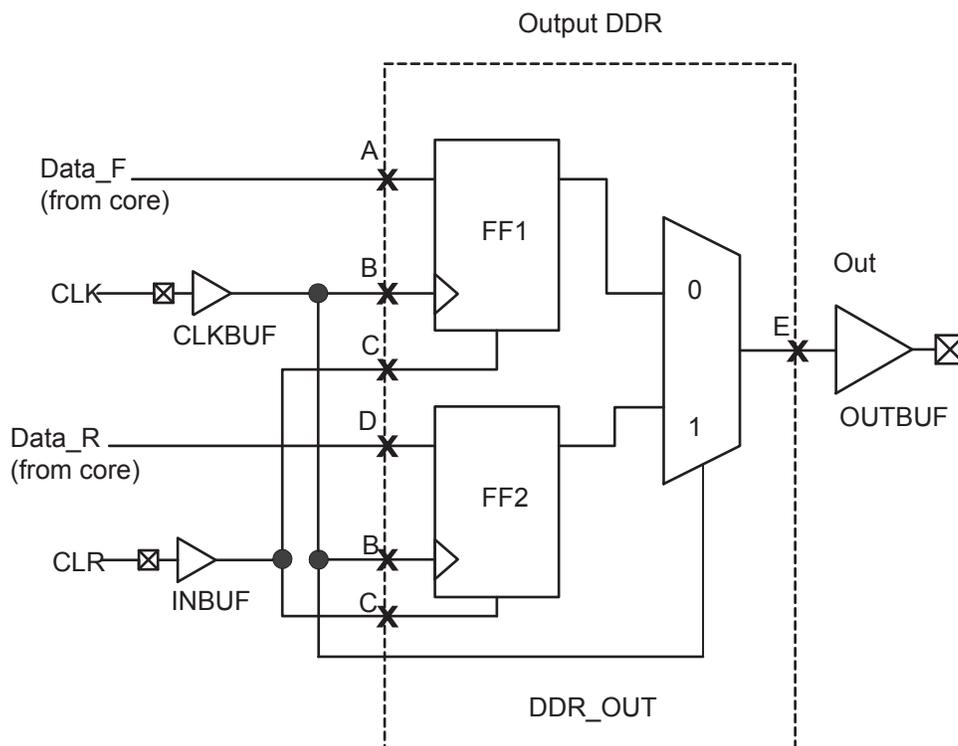
### Timing Characteristics

Table 2-87 • Output Data Register Propagation Delays  
Commercial-Case Conditions:  $T_j = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
$t_{OCLKQ}$	Clock-to-Q of the Output Data Register	0.59	0.67	0.79	ns
$t_{OSUD}$	Data Setup Time for the Output Data Register	0.31	0.36	0.42	ns
$t_{OHD}$	Data Hold Time for the Output Data Register	0.00	0.00	0.00	ns
$t_{OSUE}$	Enable Setup Time for the Output Data Register	0.44	0.50	0.59	ns
$t_{OHE}$	Enable Hold Time for the Output Data Register	0.00	0.00	0.00	ns
$t_{OCLR2Q}$	Asynchronous Clear-to-Q of the Output Data Register	0.80	0.91	1.07	ns
$t_{OPRE2Q}$	Asynchronous Preset-to-Q of the Output Data Register	0.80	0.91	1.07	ns
$t_{OREMCLR}$	Asynchronous Clear Removal Time for the Output Data Register	0.00	0.00	0.00	ns
$t_{ORECCLR}$	Asynchronous Clear Recovery Time for the Output Data Register	0.22	0.25	0.30	ns
$t_{OREMPRE}$	Asynchronous Preset Removal Time for the Output Data Register	0.00	0.00	0.00	ns
$t_{ORECPRE}$	Asynchronous Preset Recovery Time for the Output Data Register	0.22	0.25	0.30	ns
$t_{OWCLR}$	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.22	0.25	0.30	ns
$t_{OWPRE}$	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.22	0.25	0.30	ns
$t_{OCKMPWH}$	Clock Minimum Pulse Width High for the Output Data Register	0.36	0.41	0.48	ns
$t_{OCKMPWL}$	Clock Minimum Pulse Width Low for the Output Data Register	0.32	0.37	0.43	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

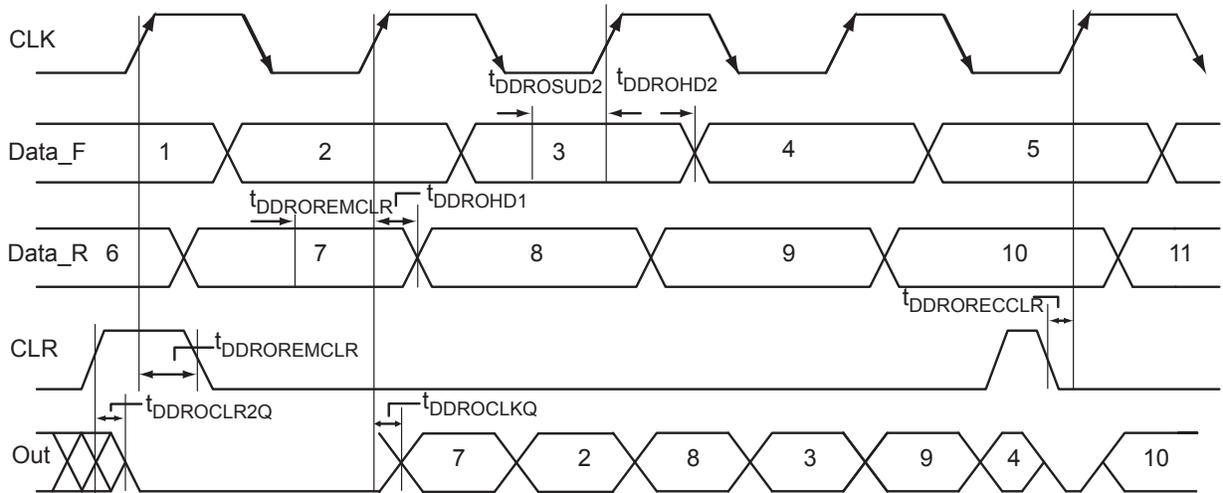
## Output DDR Module



**Figure 2-32 • Output DDR Timing Model**

**Table 2-91 • Parameter Definitions**

Parameter Name	Parameter Definition	Measuring Nodes (from, to)
$t_{DDROCLKQ}$	Clock-to-Out	B, E
$t_{DDROCLR2Q}$	Asynchronous Clear-to-Out	C, E
$t_{DDROREMCLR}$	Clear Removal	C, B
$t_{DDRORECCLR}$	Clear Recovery	C, B
$t_{DDROSUD1}$	Data Setup Data_F	A, B
$t_{DDROSUD2}$	Data Setup Data_R	D, B
$t_{DDROHD1}$	Data Hold Data_F	A, B
$t_{DDROHD2}$	Data Hold Data_R	D, B



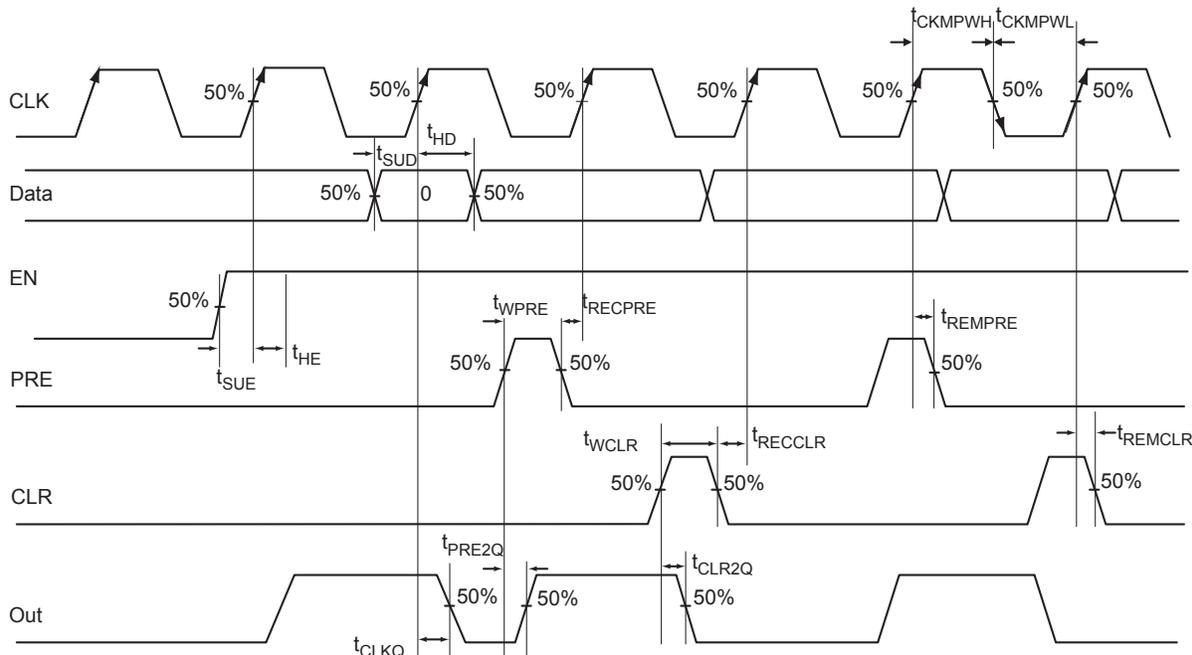
**Figure 2-33 • Output DDR Timing Diagram**

**Timing Characteristics**

**Table 2-92 • Output DDR Propagation Delays**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$

Parameter	Description	-2	-1	Std.	Units
$t_{DDROCLKQ}$	Clock-to-Out of DDR for Output DDR	0.70	0.80	0.94	ns
$t_{DDROSUD1}$	Data_F Data Setup for Output DDR	0.38	0.43	0.51	ns
$t_{DDROSUD2}$	Data_R Data Setup for Output DDR	0.38	0.43	0.51	ns
$t_{DDROHD1}$	Data_F Data Hold for Output DDR	0.00	0.00	0.00	ns
$t_{DDROHD2}$	Data_R Data Hold for Output DDR	0.00	0.00	0.00	ns
$t_{DDROCLR2Q}$	Asynchronous Clear-to-Out for Output DDR	0.80	0.91	1.07	ns
$t_{DDROEMCLR}$	Asynchronous Clear Removal Time for Output DDR	0.00	0.00	0.00	ns
$t_{DDROECCLR}$	Asynchronous Clear Recovery Time for Output DDR	0.22	0.25	0.30	ns
$t_{DDROWCLR1}$	Asynchronous Clear Minimum Pulse Width for Output DDR	0.22	0.25	0.30	ns
$t_{DDROCKMPWH}$	Clock Minimum Pulse Width High for the Output DDR	0.36	0.41	0.48	ns
$t_{DDROCKMPWL}$	Clock Minimum Pulse Width Low for the Output DDR	0.32	0.37	0.43	ns
$F_{DDOMAX}$	Maximum Frequency for the Output DDR	1404	1232	1048	MHz

*Note:* For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.



**Figure 2-37 • Timing Model and Waveforms**

### Timing Characteristics

**Table 2-94 • Register Delays**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$

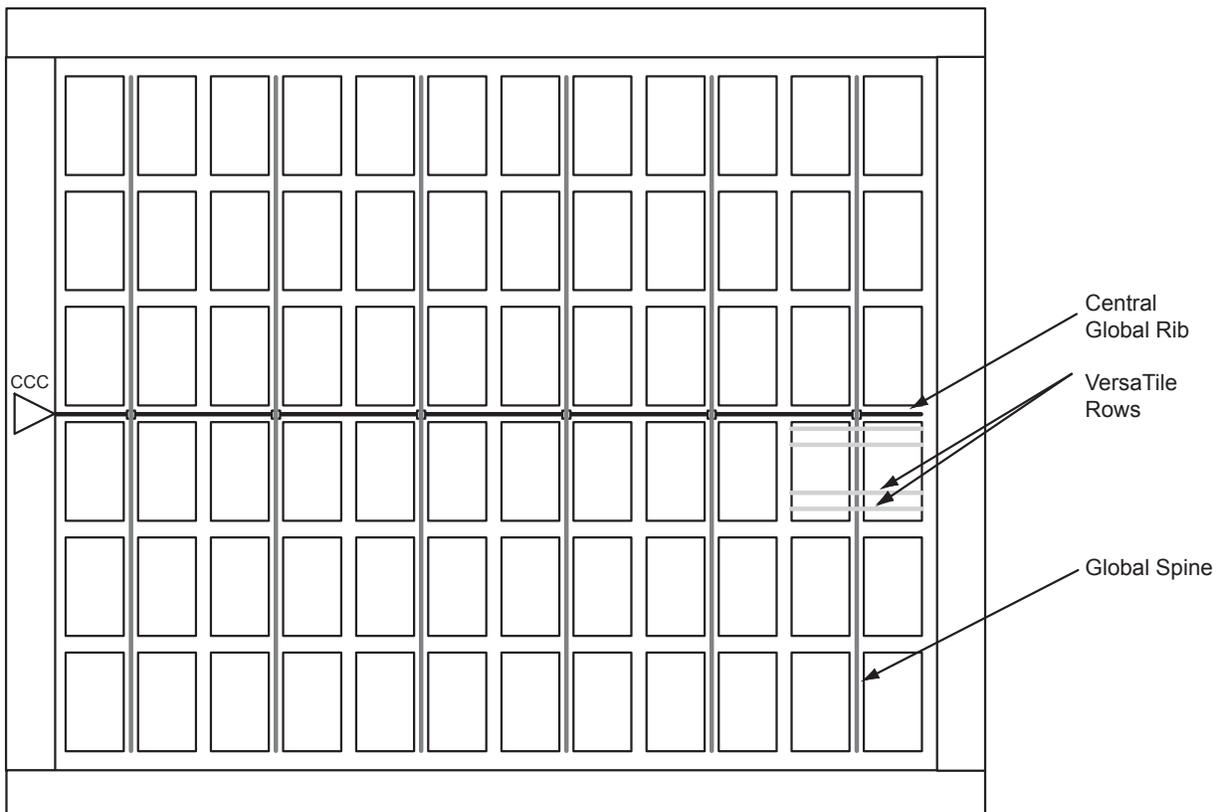
Parameter	Description	-2	-1	Std.	Units
$t_{CLKQ}$	Clock-to-Q of the Core Register	0.55	0.63	0.74	ns
$t_{SUD}$	Data Setup Time for the Core Register	0.43	0.49	0.57	ns
$t_{HD}$	Data Hold Time for the Core Register	0.00	0.00	0.00	ns
$t_{SUE}$	Enable Setup Time for the Core Register	0.45	0.52	0.61	ns
$t_{HE}$	Enable Hold Time for the Core Register	0.00	0.00	0.00	ns
$t_{CLR2Q}$	Asynchronous Clear-to-Q of the Core Register	0.40	0.45	0.53	ns
$t_{PRE2Q}$	Asynchronous Preset-to-Q of the Core Register	0.40	0.45	0.53	ns
$t_{REMCLR}$	Asynchronous Clear Removal Time for the Core Register	0.00	0.00	0.00	ns
$t_{RECCLR}$	Asynchronous Clear Recovery Time for the Core Register	0.22	0.25	0.30	ns
$t_{REMPRE}$	Asynchronous Preset Removal Time for the Core Register	0.00	0.00	0.00	ns
$t_{RECPRE}$	Asynchronous Preset Recovery Time for the Core Register	0.22	0.25	0.30	ns
$t_{WCLR}$	Asynchronous Clear Minimum Pulse Width for the Core Register	0.22	0.25	0.30	ns
$t_{WPRE}$	Asynchronous Preset Minimum Pulse Width for the Core Register	0.22	0.25	0.30	ns
$t_{CKMPWH}$	Clock Minimum Pulse Width High for the Core Register	0.32	0.37	0.43	ns
$t_{CKMPWL}$	Clock Minimum Pulse Width Low for the Core Register	0.36	0.41	0.48	ns

*Note:* For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

## Global Resource Characteristics

### A3PE600 Clock Tree Topology

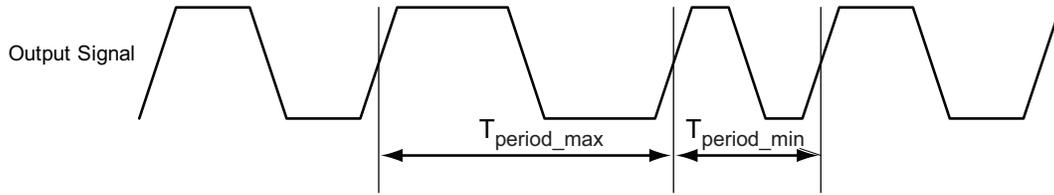
Clock delays are device-specific. Figure 2-38 is an example of a global tree used for clock routing. The global tree presented in Figure 2-38 is driven by a CCC located on the west side of the A3PE600 device. It is used to drive all D-flip-flops in the device.



**Figure 2-38 • Example of Global Tree Use in an A3PE600 Device for Clock Routing**

### Global Tree Timing Characteristics

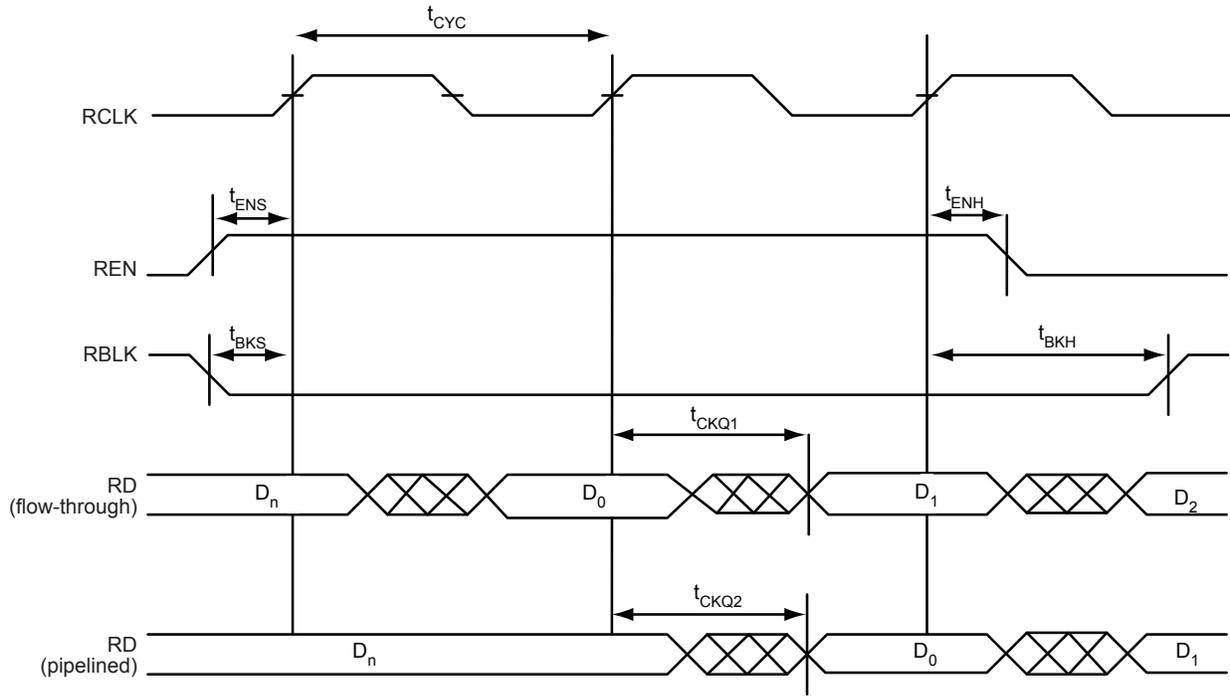
Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are I/O standard-dependent, and the clock may be driven and conditioned internally by the CCC module. For more details on clock conditioning capabilities, refer to the "Clock Conditioning Circuits" section on page 2-70. Table 2-95 on page 2-69, Table 2-96 on page 2-69, and Table 2-97 on page 2-69 present minimum and maximum global clock delays within the device. Minimum and maximum delays are measured with minimum and maximum loading.



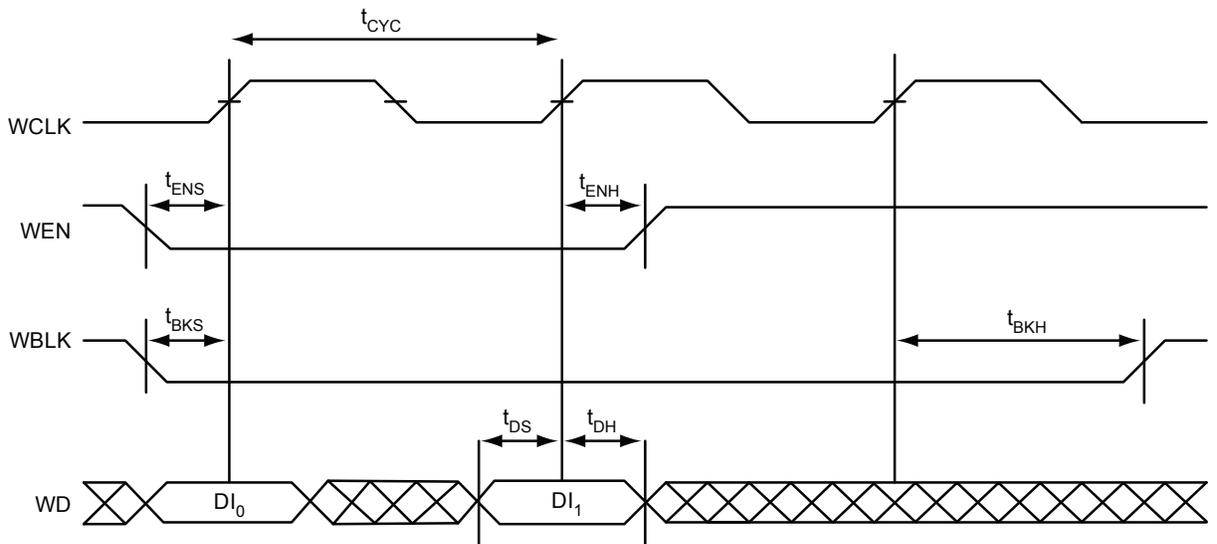
*Note:* Peak-to-peak jitter measurements are defined by  $T_{\text{peak-to-peak}} = T_{\text{period\_max}} - T_{\text{period\_min}}$ .

**Figure 2-39 • Peak-to-Peak Jitter Definition**

### Timing Waveforms



**Figure 2-47 • FIFO Read**



**Figure 2-48 • FIFO Write**

FG484	
Pin Number	A3PE1500 Function
H19	IO67PDB2V1
H20	VCC
H21	VMV2
H22	IO74PSB2V2
J1	IO212NDB7V2
J2	IO212PDB7V2
J3	VMV7
J4	IO206PDB7V1
J5	IO204PDB7V1
J6	IO210PDB7V2
J7	IO215NDB7V3
J8	VCCIB7
J9	GND
J10	VCC
J11	VCC
J12	VCC
J13	VCC
J14	GND
J15	VCCIB2
J16	IO60NDB2V0
J17	IO65NDB2V1
J18	IO65PDB2V1
J19	IO75PPB2V2
J20	GNDQ
J21	IO77PDB2V2
J22	IO79PDB2V3
K1	IO200NDB7V1
K2	IO200PDB7V1
K3	GNDQ
K4	IO206NDB7V1
K5	IO204NDB7V1
K6	IO210NDB7V2
K7	GFC1/IO192PPB7V0
K8	VCCIB7
K9	VCC
K10	GND

FG484	
Pin Number	A3PE1500 Function
K11	GND
K12	GND
K13	GND
K14	VCC
K15	VCCIB2
K16	GCC1/IO85PPB2V3
K17	IO73NDB2V2
K18	IO73PDB2V2
K19	IO81NPB2V3
K20	IO75NPB2V2
K21	IO77NDB2V2
K22	IO79NDB2V3
L1	NC
L2	IO196PDB7V0
L3	IO196NDB7V0
L4	GFB0/IO191NPB7V0
L5	GFA0/IO190NDB6V2
L6	GFB1/IO191PPB7V0
L7	VCOMPLF
L8	GFC0/IO192NPB7V0
L9	VCC
L10	GND
L11	GND
L12	GND
L13	GND
L14	VCC
L15	GCC0/IO85NPB2V3
L16	GCB1/IO86PPB2V3
L17	GCA0/IO87NPB3V0
L18	VCOMPLC
L19	GCB0/IO86NPB2V3
L20	IO81PPB2V3
L21	IO83NDB2V3
L22	IO83PDB2V3
M1	GNDQ
M2	IO185NPB6V2

FG484	
Pin Number	A3PE1500 Function
M3	IO189NDB6V2
M4	GFA2/IO189PDB6V2
M5	GFA1/IO190PDB6V2
M6	VCCPLF
M7	IO188NDB6V2
M8	GFB2/IO188PDB6V2
M9	VCC
M10	GND
M11	GND
M12	GND
M13	GND
M14	VCC
M15	GCB2/IO89PPB3V0
M16	GCA1/IO87PPB3V0
M17	GCC2/IO90PPB3V0
M18	VCCPLC
M19	GCA2/IO88PDB3V0
M20	IO88NDB3V0
M21	IO93PDB3V0
M22	NC
N1	IO185PPB6V2
N2	IO183NDB6V2
N3	VMV6
N4	GFC2/IO187PPB6V2
N5	IO184PPB6V2
N6	IO186PDB6V2
N7	IO186NDB6V2
N8	VCCIB6
N9	VCC
N10	GND
N11	GND
N12	GND
N13	GND
N14	VCC
N15	VCCIB3
N16	IO89NPB3V0

FG676	
Pin Number	A3PE1500 Function
C9	IO10PDB0V1
C10	IO16PDB0V2
C11	IO20PDB0V2
C12	IO24PDB0V3
C13	IO23PDB0V2
C14	IO28PDB0V3
C15	IO31PDB0V3
C16	IO32NDB1V0
C17	IO36NDB1V0
C18	IO37NDB1V0
C19	IO45NDB1V1
C20	IO42PPB1V1
C21	IO46NPB1V1
C22	IO48NPB1V2
C23	GBB0/IO56NPB1V3
C24	VMV1
C25	GBC2/IO60PDB2V0
C26	IO60NDB2V0
D1	IO218NDB7V3
D2	IO218PDB7V3
D3	GND
D4	VMV7
D5	IO221NDB7V3
D6	GAC0/IO02NDB0V0
D7	GAC1/IO02PDB0V0
D8	IO05NDB0V0
D9	IO08PDB0V1
D10	IO12NDB0V1
D11	IO18NDB0V2
D12	IO17NDB0V2
D13	IO25NDB0V3
D14	IO29NDB0V3
D15	IO33NDB1V0
D16	IO40PDB1V1
D17	IO43NDB1V1
D18	IO47PDB1V1

FG676	
Pin Number	A3PE1500 Function
D19	IO45PDB1V1
D20	IO46PPB1V1
D21	IO48PPB1V2
D22	GBA0/IO57NPB1V3
D23	GNDQ
D24	GBB1/IO56PPB1V3
D25	GBB2/IO59PDB2V0
D26	IO59NDB2V0
E1	IO212PDB7V2
E2	IO211NDB7V2
E3	IO211PDB7V2
E4	IO220NPB7V3
E5	GNDQ
E6	GAB2/IO220PPB7V3
E7	GAB1/IO01PDB0V0
E8	IO05PDB0V0
E9	IO08NDB0V1
E10	IO12PDB0V1
E11	IO18PDB0V2
E12	IO17PDB0V2
E13	IO25PDB0V3
E14	IO29PDB0V3
E15	IO33PDB1V0
E16	IO40NDB1V1
E17	IO43PDB1V1
E18	IO47NDB1V1
E19	IO54NDB1V3
E20	IO52NDB1V2
E21	IO52PDB1V2
E22	VCCPLB
E23	GBA1/IO57PPB1V3
E24	IO63PDB2V0
E25	IO63NDB2V0
E26	IO68PDB2V1
F1	IO212NDB7V2
F2	IO203PPB7V1

FG676	
Pin Number	A3PE1500 Function
F3	IO213NDB7V2
F4	IO213PDB7V2
F5	GND
F6	VCCPLA
F7	GAB0/IO01NDB0V0
F8	GNDQ
F9	IO03PDB0V0
F10	IO13PDB0V1
F11	IO15PDB0V1
F12	IO19PDB0V2
F13	IO21PDB0V2
F14	IO27NDB0V3
F15	IO35PDB1V0
F16	IO39NDB1V0
F17	IO51PDB1V2
F18	IO53PDB1V2
F19	IO54PDB1V3
F20	VMV2
F21	VCOMPLB
F22	IO61PDB2V0
F23	IO61NDB2V0
F24	IO66PDB2V1
F25	IO66NDB2V1
F26	IO68NDB2V1
G1	IO203NPB7V1
G2	IO207NDB7V2
G3	IO207PDB7V2
G4	IO216NDB7V3
G5	IO216PDB7V3
G6	VCOMPLA
G7	VMV0
G8	VCC
G9	IO03NDB0V0
G10	IO13NDB0V1
G11	IO15NDB0V1
G12	IO19NDB0V2

FG896	
Pin Number	A3PE3000 Function
A2	GND
A3	GND
A4	IO14NPB0V1
A5	GND
A6	IO07NPB0V0
A7	GND
A8	IO09NDB0V1
A9	IO17NDB0V2
A10	IO17PDB0V2
A11	IO21NDB0V2
A12	IO21PDB0V2
A13	IO33NDB0V4
A14	IO33PDB0V4
A15	IO35NDB0V4
A16	IO35PDB0V4
A17	IO41NDB1V0
A18	IO43NDB1V0
A19	IO43PDB1V0
A20	IO45NDB1V0
A21	IO45PDB1V0
A22	IO57NDB1V2
A23	IO57PDB1V2
A24	GND
A25	IO69PPB1V3
A26	GND
A27	GBC1/IO79PPB1V4
A28	GND
A29	GND
AA1	IO256PDB6V2
AA2	IO248PDB6V1
AA3	IO248NDB6V1
AA4	IO246NDB6V1
AA5	GEA1/IO234PDB6V0
AA6	GEA0/IO234NDB6V0
AA7	IO243PPB6V1
AA8	IO245NDB6V1

FG896	
Pin Number	A3PE3000 Function
AA9	GEB1/IO235PPB6V0
AA10	VCC
AA11	IO226PPB5V4
AA12	VCCIB5
AA13	VCCIB5
AA14	VCCIB5
AA15	VCCIB5
AA16	VCCIB4
AA17	VCCIB4
AA18	VCCIB4
AA19	VCCIB4
AA20	IO174PDB4V2
AA21	VCC
AA22	IO142NPB3V3
AA23	IO144NDB3V3
AA24	IO144PDB3V3
AA25	IO146NDB3V4
AA26	IO146PDB3V4
AA27	IO147PDB3V4
AA28	IO139NDB3V3
AA29	IO139PDB3V3
AA30	IO133NDB3V2
AB1	IO256NDB6V2
AB2	IO244PDB6V1
AB3	IO244NDB6V1
AB4	IO241PDB6V0
AB5	IO241NDB6V0
AB6	IO243NPB6V1
AB7	VCCIB6
AB8	VCCPLE
AB9	VCC
AB10	IO222PDB5V3
AB11	IO218PPB5V3
AB12	IO206NDB5V1
AB13	IO206PDB5V1
AB14	IO198NDB5V0

FG896	
Pin Number	A3PE3000 Function
AB15	IO198PDB5V0
AB16	IO192NDB4V4
AB17	IO192PDB4V4
AB18	IO178NDB4V3
AB19	IO178PDB4V3
AB20	IO174NDB4V2
AB21	IO162NPB4V1
AB22	VCC
AB23	VCCPLD
AB24	VCCIB3
AB25	IO150PDB3V4
AB26	IO148PDB3V4
AB27	IO147NDB3V4
AB28	IO145PDB3V3
AB29	IO143PDB3V3
AB30	IO137PDB3V2
AC1	IO254PDB6V2
AC2	IO254NDB6V2
AC3	IO240PDB6V0
AC4	GEC1/IO236PDB6V0
AC5	IO237PDB6V0
AC6	IO237NDB6V0
AC7	VCOMPLE
AC8	GND
AC9	IO226NPB5V4
AC10	IO222NDB5V3
AC11	IO216NPB5V2
AC12	IO210NPB5V2
AC13	IO204NDB5V1
AC14	IO204PDB5V1
AC15	IO194NDB5V0
AC16	IO188NDB4V4
AC17	IO188PDB4V4
AC18	IO182PPB4V3
AC19	IO170NPB4V2
AC20	IO164NDB4V1

## 5 – Datasheet Information

### List of Changes

The following table lists critical changes that were made in each revision of the ProASIC3E datasheet.

Revision	Changes	Page
Revision 15 (June 2015)	Updated " <a href="#">ProASIC3E Ordering Information</a> ". Interchanged the positions of Y-Security Feature and I- Application (Temperature Range) (SAR 67296). Added Note "Only devices with package size greater than or equal to 5x5 are supported". Updated Commercial and Industrial Junction Temperatures (SAR 67588).	1-III
	Added the A3PE3000 package to <a href="#">Table 2-5</a> (SARs 52320 and 58737).	2-5
	Updated " <a href="#">VCCIBx I/O Supply Voltage</a> " (SAR 43323).	3-1
	Added 2 mA and 6 mA I/O short currents values in " <a href="#">I/O Short Currents IOSH/IOSL</a> " (SAR 56295). Added 2 mA and 6 mA minimum and maximum DC input and output levels in " <a href="#">Minimum and Maximum DC Input and Output Levels</a> "(SAR 56295). Added 3.3 V LVTTTL / 3.3 V LVCMOS High Slew Commercial-Case Conditions for 2 mA and 6 mA in " <a href="#">3.3 V LVTTTL / 3.3 V LVCMOS High Slew</a> " (SAR 56295). Added 3.3 V LVTTTL / 3.3 V LVCMOS Low Slew Commercial-Case Conditions for 2 mA and 6 mA in " <a href="#">3.3 V LVTTTL / 3.3 V LVCMOS Low Slew</a> " (SAR 56295).	2-22 2-24 2-25 2-25
Revision 13 (January 2013)	In the " <a href="#">Features and Benefits</a> " section, updated the <a href="#">Clock Conditioning Circuit (CCC)</a> and PLL Wide Input Frequency Range from '1.5 MHz to 200 MHz' to '1.5MHz to 350 MHz' based on <a href="#">Table 2-98</a> (SAR 22196).	1-1
	The " <a href="#">ProASIC3E Ordering Information</a> " section has been updated to mention "Y" as "Blank" mentioning "Device Does Not Include License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio" (SAR 43220).	1-III
	Added a note to " <a href="#">Recommended Operating Conditions 1</a> " table (SAR 42716): The programming temperature range supported is $T_{ambient} = 0^{\circ}C$ to $85^{\circ}C$ .	2-2
	The note in " <a href="#">ProASIC3E CCC/PLL Specification</a> " table referring the reader to SmartGen was revised to refer instead to the online help associated with the core (SAR 42571).	2-70
	Libero Integrated Design Environment (IDE) was changed to Libero System-on-Chip (SoC) throughout the document (SAR 40285). Live at Power-Up (LAPU) has been replaced with 'Instant On'.	NA
Revision 12 (September 2012)	The " <a href="#">Security</a> " section was modified to clarify that Microsemi does not support read-back of programmed data.	1-1

Revision	Changes	Page
Advance v0.5 (continued)	The "I/O User Input/Output" pin description was updated to include information on what happens when the pin is unused.	2-50
	The "JTAG Pins" section was updated to include information on what happens when the pin is unused.	2-51
	The "Programming" section was updated to include information concerning serialization.	2-53
	The "JTAG 1532" section was updated to include SAMPLE/PRELOAD information.	2-54
	The "DC and Switching Characteristics" chapter was updated with new information.	Starting on page 3-1
	Table 3-6 was updated.	3-5
	In Table 3-10, PAC4 was updated.	3-8
	Table 3-19 was updated.	3-20
	The note in Table 3-24 was updated.	3-23
	All Timing Characteristics tables were updated from LVTTTL to Register Delays	3-26 to 3-64
	The Timing Characteristics for RAM4K9, RAM512X18, and FIFO were updated.	3-74 to 3-79
	$F_{TCKMAX}$ was updated in Table 3-98.	3-80
Advance v0.4 (October 2005)	The "Packaging Tables" table was updated.	ii
Advance v0.3	Figure 2-11 was updated.	2-9
	The "Clock Resources (VersaNets)" section was updated.	2-9
	The "VersaNet Global Networks and Spine Access" section was updated.	2-9
	The "PLL Macro" section was updated.	2-15
	Figure 2-27 was updated.	2-28
	Figure 2-20 was updated.	2-19
	Table 2-5 was updated.	2-25
	Table 2-6 was updated.	2-25
	The "FIFO Flag Usage Considerations" section was updated.	2-27
	Table 2-33 was updated.	2-51
	Figure 2-24 was updated.	2-31
	The "Cold-Sparing Support" section is new.	2-34
	Table 2-45 was updated.	2-64
	Table 2-48 was updated.	2-81
	Pin descriptions in the "JTAG Pins" section were updated.	2-51
	The "Pin Descriptions" section was updated.	2-50
	Table 3-7 was updated.	3-6

Revision	Changes	Page
Advance v0.3 (continued)	The "Methodology" section was updated.	3-9
	The A3PE3000 "208-Pin PQFP" pin table was updated.	4-6

## Datasheet Categories

### **Categories**

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device, as highlighted in the "[ProASIC3E Device Status](#)" table on page II, is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

#### **Product Brief**

The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

#### **Advance**

This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

#### **Preliminary**

The datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.

#### **Production**

This version contains information that is considered to be final.

### **Export Administration Regulations (EAR)**

The products described in this document are subject to the Export Administration Regulations (EAR). They could require an approved export license prior to export from the United States. An export includes release of product or disclosure of technology to a foreign national inside or outside the United States.

## **Safety Critical, Life Support, and High-Reliability Applications Policy**

The products described in this advance status document may not have completed the Microsemi qualification process. Products may be amended or enhanced during the product introduction and qualification process, resulting in changes in device functionality or performance. It is the responsibility of each customer to ensure the fitness of any product (but especially a new product) for a particular purpose, including appropriateness for safety-critical, life-support, and other high-reliability applications. Consult the Microsemi SoC Products Group Terms and Conditions for specific liability exclusions relating to life-support applications. A reliability report covering all of the SoC Products Group's products is available at [Microsemi SoC Reliability Report](#). Microsemi also offers a variety of enhanced qualification and lot acceptance screening procedures. Contact your local sales office for additional reliability information.